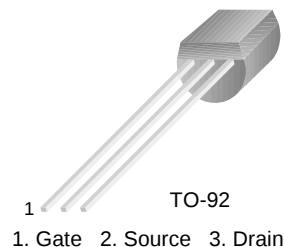


BF245A/BF245B/BF245C

N-Channel Amplifiers

- This device is designed for VHF/UHF amplifiers.
- Sourced from process 50.



Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

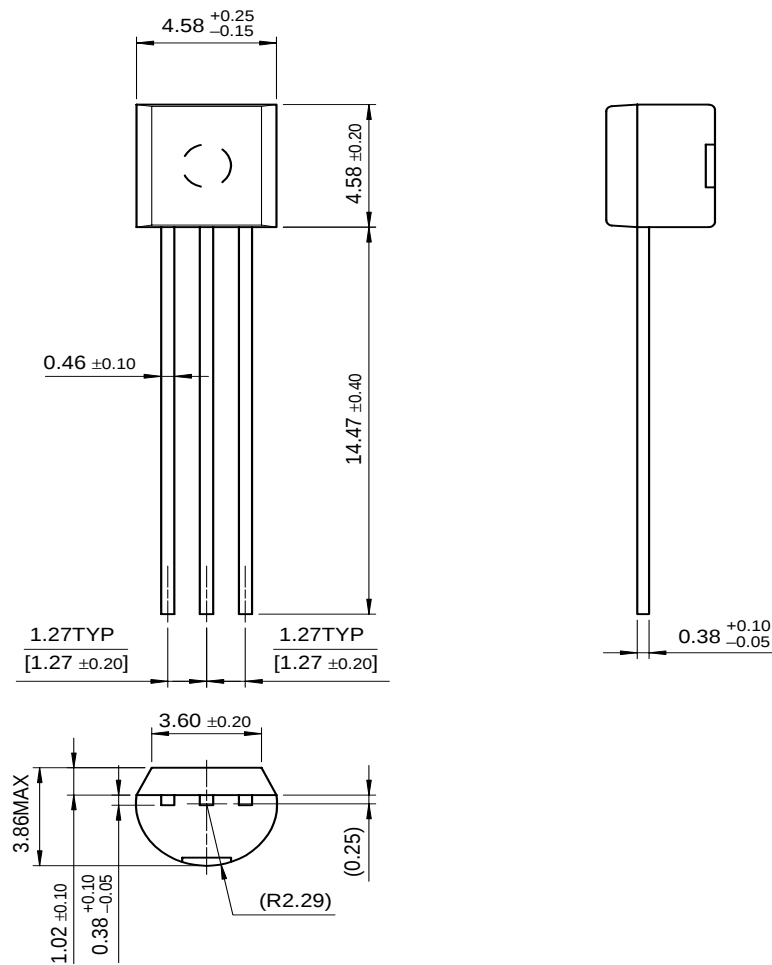
Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	30	V
V_{GS}	Gate-Source Voltage	-30	V
I_{GF}	Forward Gate Current	10	mA
P_D	Total Device Dissipation @ $T_A=25^\circ\text{C}$ Derate above 25°C	350 2.8	mW mW/ $^\circ\text{C}$
T_J, T_{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$V_{DS} = 0, I_G = 1\mu\text{A}$	-30		V
V_{GS}	Gate-Source BF245A BF245B BF245C	$V_{DS} = 15\text{V}, I_D = 200\mu\text{A}$	-0.4 -1.6 -3.2	-2.2 -3.8 -7.5	V
$V_{GS(off)}$	Gate-Source Cut-off Voltage	$V_{DS} = 15\text{V}, I_D = 10\text{nA}$	-0.5	-8	V
I_{GSS}	Gate Reverse Current	$V_{GS} = -20\text{V}, V_{DS} = 0$		-5	nA
On Characteristics					
I_{DSS}	Zero-Gate Voltage Drain Current BF245A BF245B BF245C	$V_{GS} = 15\text{V}, V_{DS} = 0$	2 6 12	6.5 15 25	mA
On Characteristics					
g_{fs}	Common Source Forward Transconductance	$V_{GS} = 15\text{V}, V_{DS} = 0, f = 1\text{KHz}$	3	6.5	mmhos

Package Dimensions

TO-92



Dimensions in Millimeters

BF245A/BF245B/BF245C

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- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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